<u>MOSFET</u> – Power 170 mAmps, 100 Volts

N-Channel SOT-23

BSS123LT1G, BVSS123LT1G

Features

- BVSS Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	100	Vdc
Gate–Source Voltage – Continuous – Non–repetitive (t _p ≤ 50 μs)	V _{GS} V _{GSM}	±20 ±40	Vdc Vpk
Drain Current – Continuous (Note 1) – Pulsed (Note 2)	I _D I _{DM}	0.17 0.68	Adc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 3) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R _{θJA}	556	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

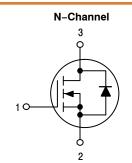
1. The Power Dissipation of the package may result in a lower continuous drain current.

2. Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

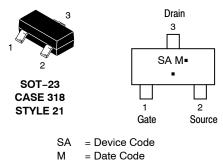
3. FR–5 = 1.0 \times 0.75 \times 0.062 in.



 $R_{DS(on)} = 6 \Omega$



MARKING DIAGRAM & PIN ASSIGNMENT



⁼ Pb-Free Package

(Note: Microdot may be in either location)

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*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

BSS123LT1G, BVSS123LT1G

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Charac	teristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain–Source Breakdown Voltage (V_{GS} = 0, I_D = 250 μ Adc)		V _{(BR)DSS}	100	_	_	Vdc
Zero Gate Voltage Drain Current $(V_{GS} = 0, V_{DS} = 100 \text{ Vdc})$ $T_J = 25^{\circ}\text{C}$ $T_J = 125^{\circ}\text{C}$		I _{DSS}		_	15 60	μAdc
Gate-Body Leakage Current (V _{GS} = 20 Vdc, V _{DS} = 0)		I _{GSS}	-	-	50	nAdc
ON CHARACTERISTICS (Note 4)						
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 1.0 \text{ mAdc})$		V _{GS(th)}	1.6	-	2.6	Vdc
Static Drain–Source On–Resistance $(V_{GS} = 10 \text{ Vdc}, I_D = 100 \text{ mAdc})$		r _{DS(on)}	-	-	6.0	Ω
Forward Transconductance $(V_{DS} = 25 \text{ Vdc}, I_D = 100 \text{ mAdc})$		9fs	80	-	-	mmhos
DYNAMIC CHARACTERISTICS						
Input Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)		C _{iss}	-	20	-	pF
Output Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)		C _{oss}	-	9.0	-	pF
Reverse Transfer Capacitance $(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0, f = 1.0 \text{ MHz})$		C _{rss}	-	4.0	-	pF
SWITCHING CHARACTERISTICS ⁽⁴⁾					-	
Turn-On Delay Time	$(V_{CC} = 30 \text{ Vdc}, I_C = 0.28 \text{ Adc}, \\ V_{GS} = 10 \text{ Vdc}, R_{GS} = 50 \Omega)$	t _{d(on)}	-	20	-	ns
Turn-Off Delay Time		t _{d(off)}	-	40	-	ns
REVERSE DIODE						
Diode Forward On–Voltage (I _D = 0.34 Adc, V _{GS} = 0 Vdc)		V _{SD}	-	-	1.3	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

ORDERING INFORMATION

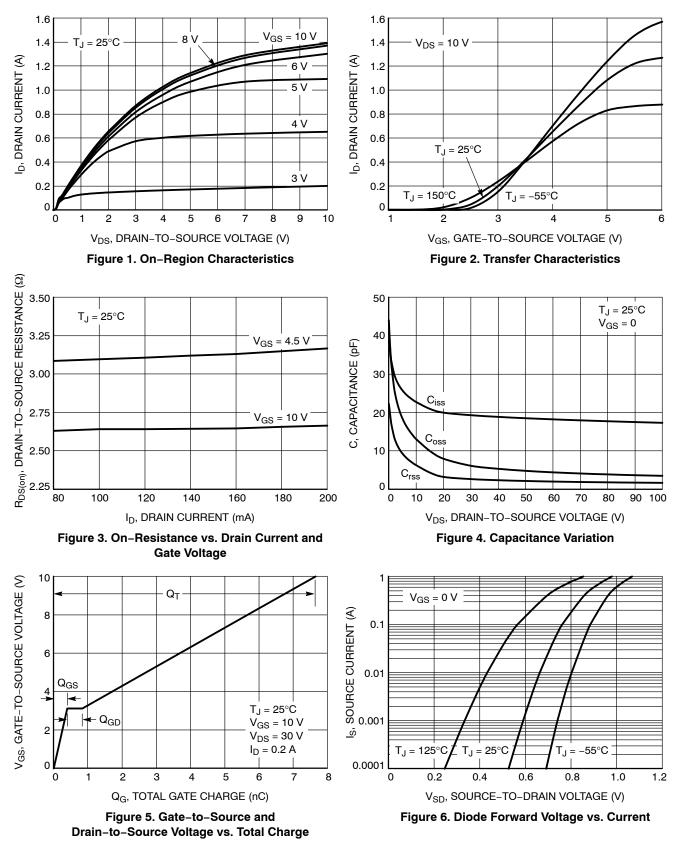
Device	Package	Shipping [†]
BSS123LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BVSS123LT1G*	SOT-23 (Pb-Free)	3,000 / Tape & Reel
BSS123LT7G	SOT-23 (Pb-Free)	3,500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *BVSS Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP

Capable.

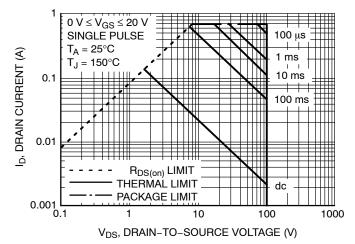
BSS123LT1G, BVSS123LT1G

TYPICAL ELECTRICAL CHARACTERISTICS

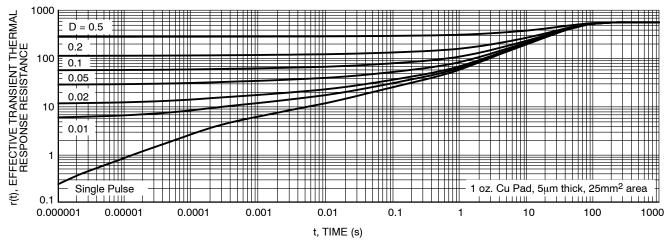


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TYPICAL ELECTRICAL CHARACTERISTICS













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